

Welcome to E-XFL.COM

Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

E·XFI

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	276480
Number of I/O	119
Number of Gates	1500000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	256-LBGA
Supplier Device Package	256-FPBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/afs1500-1fg256i

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

The system application, Level 3, is the larger user application that utilizes one or more applets. Designing at the highest level of abstraction supported by the Fusion technology stack, the application can be easily created in FPGA gates by importing and configuring multiple applets.

In fact, in some cases an entire FPGA system design can be created without any HDL coding.

An optional MCU enables a combination of software and HDL-based design methodologies. The MCU can be on-chip or off-chip as system requirements dictate. System portioning is very flexible, allowing the MCU to reside above the applets or to absorb applets, or applets and backbone, if desired.

The Fusion technology stack enables a very flexible design environment. Users can engage in design across a continuum of abstraction from very low to very high.

Core Architecture

VersaTile

Based upon successful ProASIC3/E logic architecture, Fusion devices provide granularity comparable to gate arrays. The Fusion device core consists of a sea-of-VersaTiles architecture.

As illustrated in Figure 2-2, there are four inputs in a logic VersaTile cell, and each VersaTile can be configured using the appropriate flash switch connections:

- Any 3-input logic function
- Latch with clear or set
- · D-flip-flop with clear or set
- Enable D-flip-flop with clear or set (on a 4th input)

VersaTiles can flexibly map the logic and sequential gates of a design. The inputs of the VersaTile can be inverted (allowing bubble pushing), and the output of the tile can connect to high-speed, very-long-line routing resources. VersaTiles and larger functions are connected with any of the four levels of routing hierarchy.

When the VersaTile is used as an enable D-flip-flop, the SET/CLR signal is supported by a fourth input, which can only be routed to the core cell over the VersaNet (global) network.

The output of the VersaTile is F2 when the connection is to the ultra-fast local lines, or YL when the connection is to the efficient long-line or very-long-line resources (Figure 2-2).



Note: *This input can only be connected to the global clock distribution network.

Figure 2-2 • Fusion Core VersaTile

Routing Architecture

The routing structure of Fusion devices is designed to provide high performance through a flexible four-level hierarchy of routing resources: ultra-fast local resources; efficient long-line resources; high-speed very-long-line resources; and the high-performance VersaNet networks.

The ultra-fast local resources are dedicated lines that allow the output of each VersaTile to connect directly to every input of the eight surrounding VersaTiles (Figure 2-8). The exception to this is that the SET/CLR input of a VersaTile configured as a D-flip-flop is driven only by the VersaNet global network.

The efficient long-line resources provide routing for longer distances and higher-fanout connections. These resources vary in length (spanning one, two, or four VersaTiles), run both vertically and horizontally, and cover the entire Fusion device (Figure 2-9 on page 2-9). Each VersaTile can drive signals onto the efficient long-line resources, which can access every input of every VersaTile. Active buffers are inserted automatically by routing software to limit loading effects.

The high-speed very-long-line resources, which span the entire device with minimal delay, are used to route very long or high-fanout nets: length ± 12 VersaTiles in the vertical direction and length ± 16 in the horizontal direction from a given core VersaTile (Figure 2-10 on page 2-10). Very long lines in Fusion devices, like those in ProASIC3 devices, have been enhanced. This provides a significant performance boost for long-reach signals.

The high-performance VersaNet global networks are low-skew, high-fanout nets that are accessible from external pins or from internal logic (Figure 2-11 on page 2-11). These nets are typically used to distribute clocks, reset signals, and other high-fanout nets requiring minimum skew. The VersaNet networks are implemented as clock trees, and signals can be introduced at any junction. These can be employed hierarchically, with signals accessing every input on all VersaTiles.







Table 2-16 • RTC Control/Status Register

Bit	Name	Description			
7	rtc_rst	RTC Reset			
		1 – Resets the RTC			
		0 – Deassert reset on after two ACM_CLK cycle.			
6	cntr_en	Counter Enable	0		
		1 – Enables the counter; rtc_rst must be deasserted as well. First counter increments after 64 RTCCLK positive edges.			
		0 – Disables the crystal prescaler but does not reset the counter value. Counter value can only be updated when the counter is disabled.			
5	vr_en_mat	Voltage Regulator Enable on Match	0		
		1 – Enables RTCMATCH and RTCPSMMATCH to output 1 when the counter value equals the Match Register value. This enables the 1.5 V voltage regulator when RTCPSMMATCH connects to the RTCPSMMATCH signal in VRPSM.			
		0 – RTCMATCH and RTCPSMMATCH output 0 at all times.			
4:3	xt_mode[1:0]	Crystal Mode	00		
		Controls RTCXTLMODE[1:0]. Connects to RTC_MODE signal in XTLOSC. XTL_MODE uses this value when xtal_en is 1. See the "Crystal Oscillator" section on page 2-20 for mode configuration.			
2	rst_cnt_omat	Reset Counter on Match	0		
		1 – Enables the sync clear of the counter when the counter value equals the Match Register value. The counter clears on the rising edge of the clock. If all the Match Registers are set to 0, the clear is disabled.			
		0 – Counter increments indefinitely			
1	rstb_cnt	Counter Reset, active Low	0		
		0 - Resets the 40-bit counter value			
0	xtal_en	Crystal Enable	0		
		Controls RTCXTLSEL. Connects to SELMODE signal in XTLOSC.			
		0 – XTLOSC enables control by FPGA_EN; xt_mode is not used. Sleep mode requires this bit to equal 0.			
		1 – Enables XTLOSC, XTL_MODE control by xt_mode			
		Standby mode requires this bit to be set to 1.			
		See the "Crystal Oscillator" section on page 2-20 for further details on SELMODE configuration.			





Figure 2-54 • One Port Write / Other Port Read Same



Figure 2-55 • RAM Reset. Applicable to both RAM4K9 and RAM512x18.

Analog MUX Channel	Signal	Analog Quad Number
16	AV5	
17	AC5	Analog Quad 5
18	AT5	
19	AV6	
20	AC6	Analog Quad 6
21	AT6	
22	AV7	
23	AC7	Analog Quad 7
24	AT7	
25	AV8	
26	AC8	Analog Quad 8
27	AT8	
28	AV9	
29	AC9	Analog Quad 9
30	AT9	
31	Internal temperature monitor	

Table 2-40 • Analog MUX Channels (continued)

The ADC can be powered down independently of the FPGA core, as an additional control or for powersaving considerations, via the PWRDWN pin of the Analog Block. The PWRDWN pin controls only the comparators in the ADC.

ADC Modes

The Fusion ADC can be configured to operate in 8-, 10-, or 12-bit modes, power-down after conversion, and dynamic calibration. This is controlled by MODE[3:0], as defined in Table 2-41 on page 2-106.

The output of the ADC is the RESULT[11:0] signal. In 8-bit mode, the Most Significant 8 Bits RESULT[11:4] are used as the ADC value and the Least Significant 4 Bits RESULT[3:0] are logical '0's. In 10-bit mode, RESULT[11:2] are used the ADC value and RESULT[1:0] are logical 0s.

Name	Bits	Function			
MODE	3	 0 – Internal calibration after every conversion; two ADCCLK cycles are used after the conversion. 1 – No calibration after every conversion 			
MODE	2	0 – Power-down after conversion 1 – No Power-down after conversion			
MODE	1:0	00 – 10-bit 01 – 12-bit 10 – 8-bit 11 – Unused			

Table 2-68 • I/O Bank Support by Device

I/O Bank	AFS090	AFS250	AFS600	AFS1500
Standard I/O	Ν	Ν	_	-
Advanced I/O	E, W	E, W	E, W	E, W
Pro I/O	-	_	Ν	Ν
Analog Quad	S	S	S	S

Note: E = *East side of the device*

W = West side of the device

N = North side of the device

S = South side of the device

Table 2-69 • Fusion VCCI Voltages and Compatible Standards

VCCI (typical)	Compatible Standards
3.3 V	LVTTL/LVCMOS 3.3, PCI 3.3, SSTL3 (Class I and II),* GTL+ 3.3, GTL 3.3,* LVPECL
2.5 V	LVCMOS 2.5, LVCMOS 2.5/5.0, SSTL2 (Class I and II),* GTL+ 2.5,* GTL 2.5,* LVDS, BLVDS, M-LVDS
1.8 V	LVCMOS 1.8
1.5 V	LVCMOS 1.5, HSTL (Class I),* HSTL (Class II)*

Note: *I/O standard supported by Pro I/O banks.

Table 2-70 • Fusion VREF Voltages and Compatible Standards*

VREF (typical)	Compatible Standards
1.5 V	SSTL3 (Class I and II)
1.25 V	SSTL2 (Class I and II)
1.0 V	GTL+ 2.5, GTL+ 3.3
0.8 V	GTL 2.5, GTL 3.3
0.75 V	HSTL (Class I), HSTL (Class II)

Note: *I/O standards supported by Pro I/O banks.

Table 2-82 • Advanced I/O Default Attributes

I/O Standards	SLEW (output only)	OUT_DRIVE (output only)	SKEW (tribuf and bibuf only)	RES_PULL	OUT_LOAD (output only)	COMBINE_REGISTER
LVTTL/LVCMOS 3.3 V	Refer to the following	Refer to the following tables	Off	None	35 pF	-
LVCMOS 2.5 V	information:	Table 2-78 on page 2-152	Off	None	35 pF	-
LVCMOS 2.5/5.0 V	Table 2-78 on page 2-152	Table 2-79 on page 2-152	Off	None	35 pF	-
LVCMOS 1.8 V	Table 2-79 on page 2-152	Table 2-80 on page 2-152	Off	None	35 pF	-
LVCMOS 1.5 V	Table 2-80 on page 2-152		Off	None	35 pF	-
PCI (3.3 V)			Off	None	10 pF	-
PCI-X (3.3 V)			Off	None	10 pF	-
LVDS, BLVDS, M-LVDS			Off	None	_	_
LVPECL			Off	None	-	-



I/O Standard	Input/Output Supply Voltage (VCCI_TYP)	Input Reference Voltage (VREF_TYP)	Board Termination Voltage (VTT_TYP)
LVTTL/LVCMOS 3.3 V	3.30 V	-	-
LVCMOS 2.5 V	2.50 V	-	-
LVCMOS 2.5 V / 5.0 V Input	2.50 V	-	-
LVCMOS 1.8 V	1.80 V	-	-
LVCMOS 1.5 V	1.50 V	-	-
PCI 3.3 V	3.30 V	-	-
PCI-X 3.3 V	3.30 V	-	-
GTL+ 3.3 V	3.30 V	1.00 V	1.50 V
GTL+ 2.5 V	2.50 V	1.00 V	1.50 V
GTL 3.3 V	3.30 V	0.80 V	1.20 V
GTL 2.5 V	2.50 V	0.80 V	1.20 V
HSTL Class I	1.50 V	0.75 V	0.75 V
HSTL Class II	1.50 V	0.75 V	0.75 V
SSTL3 Class I	3.30 V	1.50 V	1.50 V
SSTL3 Class II	3.30 V	1.50 V	1.50 V
SSTL2 Class I	2.50 V	1.25 V	1.25 V
SSTL2 Class II	2.50 V	1.25 V	1.25 V
LVDS, BLVDS, M-LVDS	2.50 V	-	-
LVPECL	3.30 V	-	-

Table 2-83 • Fusion Pro I/O Supported Standards and Corresponding VREF and VTT Voltages



Table 2-96 • I/O Output Buffer Maximum Resistances ¹ (continued)

Standard	Drive Strength	R _{PULL-DOWN} (ohms) ²	R _{PULL-UP} (ohms) ³				
Applicable to Standard I/O Banks							
3.3 V LVTTL / 3.3 V LVCMOS	2 mA	100	300				
	4 mA	100	300				
	6 mA	50	150				
	8 mA	50	150				
2.5 V LVCMOS	2 mA	100	200				
	4 mA	100	200				
	6 mA	50	100				
	8 mA	50	100				
1.8 V LVCMOS	2 mA	200	225				
	4 mA	100	112				
1.5 V LVCMOS	2 mA	200	224				

Notes:

1. These maximum values are provided for informational reasons only. Minimum output buffer resistance values depend on VCC, drive strength selection, temperature, and process. For board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the Microsemi SoC Products Group website: http://www.microsemi.com/soc/techdocs/models/ibis.html.

2. R_(PULL-DOWN-MAX) = VOLspec / I_{OLspec}

3. R_(PULL-UP-MAX) = (VCCImax – VOHspec) / IOHspec

Table 2-97 • I/O Weak Pull-Up/Pull-Down Resistances Minimum and Maximum Weak Pull-Up/Pull-Down Resistance Values

	R _(WEAK PULL-UP) 1 (ohms)		R _(WEAK PULL-DOWN) 2 (ohms)	
VCCI	Min.	Max.	Min.	Max.
3.3 V	10 k	45 k	10 k	45 k
2.5 V	11 k	55 k	12 k	74 k
1.8 V	18 k	70 k	17 k	110 k
1.5 V	19 k	90 k	19 k	140 k

Notes:

R_(WEAK PULL-UP-MAX) = (VCCImax – VOHspec) / I_{WEAK PULL-UP-MIN}
 R_(WEAK PULL-DOWN-MAX) = VOLspec / I_{WEAK PULL-DOWN-MIN}



Single-Ended I/O Characteristics

3.3 V LVTTL / 3.3 V LVCMOS

Low-Voltage Transistor–Transistor Logic is a general-purpose standard (EIA/JESD) for 3.3 V applications. It uses an LVTTL input buffer and push-pull output buffer. The 3.3 V LVCMOS standard is supported as part of the 3.3 V LVTTL support.

Table 2-102	• Minimum	and Maximum	DC Input	and Output	l evels
10016 2-102	• Willing the second		DO inpui	and Output	. LEVEIJ

3.3 V LVTTL / 3.3 V LVCMOS	v	IL	v	ІН	VOL	VOH	IOL	юн	IOSL	IOSH	IIL ¹	IIH ²
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA ³	Max. mA ³	μA ⁴	μA ⁴
Applicable to P	Applicable to Pro I/O Banks											
4 mA	-0.3	0.8	2	3.6	0.4	2.4	4	4	27	25	10	10
8 mA	-0.3	0.8	2	3.6	0.4	2.4	8	8	54	51	10	10
12 mA	-0.3	0.8	2	3.6	0.4	2.4	12	12	109	103	10	10
16 mA	-0.3	0.8	2	3.6	0.4	2.4	16	16	127	132	10	10
24 mA	-0.3	0.8	2	3.6	0.4	2.4	24	24	181	268	10	10
Applicable to A	dvanced	I/O Bank	s									
2 mA	-0.3	0.8	2	3.6	0.4	2.4	2	2	27	25	10	10
4 mA	-0.3	0.8	2	3.6	0.4	2.4	4	4	27	25	10	10
6 mA	-0.3	0.8	2	3.6	0.4	2.4	6	6	54	51	10	10
8 mA	-0.3	0.8	2	3.6	0.4	2.4	8	8	54	51	10	10
12 mA	-0.3	0.8	2	3.6	0.4	2.4	12	12	109	103	10	10
16 mA	-0.3	0.8	2	3.6	0.4	2.4	16	16	127	132	10	10
24 mA	-0.3	0.8	2	3.6	0.4	2.4	24	24	181	268	10	10
Applicable to S	tandard I	/O Banks					•				•	
2 mA	-0.3	0.8	2	3.6	0.4	2.4	2	2	27	25	10	10
4 mA	-0.3	0.8	2	3.6	0.4	2.4	4	4	27	25	10	10
6 mA	-0.3	0.8	2	3.6	0.4	2.4	6	6	54	51	10	10
8 mA	-0.3	0.8	2	3.6	0.4	2.4	8	8	54	51	10	10

Notes:

1. IIL is the input leakage current per I/O pin over recommended operation conditions where –0.3 V < VIN < VIL.

2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.

3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.

4. Currents are measured at 85°C junction temperature.

5. Software default selection highlighted in gray.







Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C _{LOAD} (pF)
0	3.3	1.4	-	35

Note: *Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

Timing Characteristics

Table 2-104 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew

Commercial Temperature Range Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V Applicable to Pro I/Os

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{zH}	t _{LZ}	t _{HZ}	t _{zLS}	t _{zHS}	Units
4 mA	Std.	0.66	11.01	0.04	1.20	1.57	0.43	11.21	9.05	2.69	2.44	13.45	11.29	ns
	-1	0.56	9.36	0.04	1.02	1.33	0.36	9.54	7.70	2.29	2.08	11.44	9.60	ns
	-2	0.49	8.22	0.03	0.90	1.17	0.32	8.37	6.76	2.01	1.82	10.04	8.43	ns
8 mA	Std.	0.66	7.86	0.04	1.20	1.57	0.43	8.01	6.44	3.04	3.06	10.24	8.68	ns
	-1	0.56	6.69	0.04	1.02	1.33	0.36	6.81	5.48	2.58	2.61	8.71	7.38	ns
	-2	0.49	5.87	0.03	0.90	1.17	0.32	5.98	4.81	2.27	2.29	7.65	6.48	ns
12 mA	Std.	0.66	6.03	0.04	1.20	1.57	0.43	6.14	5.02	3.28	3.47	8.37	7.26	ns
	-1	0.56	5.13	0.04	1.02	1.33	0.36	5.22	4.27	2.79	2.95	7.12	6.17	ns
	-2	0.49	4.50	0.03	0.90	1.17	0.32	4.58	3.75	2.45	2.59	6.25	5.42	ns
16 mA	Std.	0.66	5.62	0.04	1.20	1.57	0.43	5.72	4.72	3.32	3.58	7.96	6.96	ns
	-1	0.56	4.78	0.04	1.02	1.33	0.36	4.87	4.02	2.83	3.04	6.77	5.92	ns
	-2	0.49	4.20	0.03	0.90	1.17	0.32	4.27	3.53	2.48	2.67	5.94	5.20	ns
24 mA	Std.	0.66	5.24	0.04	1.20	1.57	0.43	5.34	4.69	3.39	3.96	7.58	6.93	ns
	-1	0.56	4.46	0.04	1.02	1.33	0.36	4.54	3.99	2.88	3.37	6.44	5.89	ns
	-2	0.49	3.92	0.03	0.90	1.17	0.32	3.99	3.50	2.53	2.96	5.66	5.17	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

Table 2-117 • 2.5 V LVCMOS High Slew
Commercial Temperature Range Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 2.3 V
Applicable to Standard I/Os

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{EOUT}	t _{ZL}	t _{zH}	t _{LZ}	t _{HZ}	Units
2 mA	Std.	0.66	8.20	0.04	1.29	0.43	7.24	8.20	2.03	1.91	ns
	–1	0.56	6.98	0.04	1.10	0.36	6.16	6.98	1.73	1.62	ns
	-2	0.49	6.13	0.03	0.96	0.32	5.41	6.13	1.52	1.43	ns
4 mA	Std.	0.66	8.20	0.04	1.29	0.43	7.24	8.20	2.03	1.91	ns
	-1	0.56	6.98	0.04	1.10	0.36	6.16	6.98	1.73	1.62	ns
	-2	0.49	6.13	0.03	0.96	0.32	5.41	6.13	1.52	1.43	ns
6 mA	Std.	0.66	4.77	0.04	1.29	0.43	4.55	4.77	2.38	2.55	ns
	-1	0.56	4.05	0.04	1.10	0.36	3.87	4.05	2.03	2.17	ns
	-2	0.49	3.56	0.03	0.96	0.32	3.40	3.56	1.78	1.91	ns
8 mA	Std.	0.66	4.77	0.04	1.29	0.43	4.55	4.77	2.38	2.55	ns
	-1	0.56	4.05	0.04	1.10	0.36	3.87	4.05	2.03	2.17	ns
	-2	0.49	3.56	0.03	0.96	0.32	3.40	3.56	1.78	1.91	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

Symbol	Parameter	Commercial	Industrial	Units	
AV, AC	Unpowered, ADC reset asserted or unconfigured	-11.0 to 12.6	-11.0 to 12.0	V	
	Analog input (+16 V to +2 V prescaler range)	-0.4 to 12.6	6 –0.4 to 12.0		
	Analog input (+1 V to +0.125 V prescaler range)	-0.4 to 3.75	-0.4 to 3.75	V	
	Analog input (–16 V to –2 V prescaler range)	-11.0 to 0.4	-11.0 to 0.4	V	
	Analog input (–1 V to –0.125 V prescaler range)	-3.75 to 0.4	-3.75 to 0.4	V	
	Analog input (direct input to ADC)	-0.4 to 3.75	-0.4 to 3.75	V	
	Digital input	-0.4 to 12.6	-0.4 to 12.0	V	
AG	Unpowered, ADC reset asserted or unconfigured	-11.0 to 12.6	-11.0 to 12.0	V	
	Low Current Mode (1 μ A, 3 μ A, 10 μ A, 30 μ A)	-0.4 to 12.6	-0.4 to 12.0	V	
	Low Current Mode (–1 μΑ, –3 μΑ, –10 μΑ, –30 μΑ)	-11.0 to 0.4	-11.0 to 0.4	V	
	High Current Mode ³	-11.0 to 12.6	-11.0 to 12.0	V	
AT	Unpowered, ADC reset asserted or unconfigured	–0.4 to 16.0	-0.4 to 15.0	V	
	Analog input (+16 V, 4 V prescaler range)	-0.4 to 16.0	-0.4 to 15.0	V	
	Analog input (direct input to ADC)	-0.4 to 3.75	-0.4 to 3.75	V	
	Digital input	-0.4 to 16.0	-0.4 to 15.0	V	
T _{STG} ⁴	Storage temperature	-65	°C		
T _J ⁴	Junction temperature	+	125	°C	

Table 3-1 •	Absolute	Maximum	Ratings	(continued)
-------------	----------	---------	---------	-------------

Notes:

1. The device should be operated within the limits specified by the datasheet. During transitions, the input signal may undershoot or overshoot according to the limits shown in Table 3-4 on page 3-4.

2. Analog data not valid beyond 3.65 V.

3. The high current mode has a maximum power limit of 20 mW. Appropriate current limit resistors must be used, based on voltage on the pad.

4. For flash programming and retention maximum limits, refer to Table 3-5 on page 3-5. For recommended operating limits refer to Table 3-2 on page 3-3.

Parameter	Description	Conditions	Temp.	Min	Тур	Мах	Unit
ICC ¹	1.5 V quiescent current	Operational standby ⁴ ,	T _J = 25°C		5	7.5	mA
		VCC = 1.575 V	T _J = 85°C		6.5	20	mA
			T _J = 100°C		14	48	mA
		Standby mode ⁵ or Sleep mode ⁶ , V _{CC} = 0 V			0	0	μA
ICC33 ²	3.3 V analog supplies	Operational standby ⁴ ,	T _J = 25°C		9.8	12	mA
	current	VCC33 = 3.63 V	T _J = 85°C		9.8	12	mA
			T _J = 100°C		10.7	15	mA
		Operational standby, only	T _J = 25°C		0.30	2	mA
		output ON, VCC33 = 3.63 V	T _J = 85°C		0.30	2	mA
			T _J = 100°C		0.45	2	mA
		Standby mode ⁵ ,	T _J = 25°C		2.9	2.9	mA
		VCC33 = 3.63 V	T _J = 85°C		2.9	3.0	mA
			T _J = 100°C		3.5	6	mA
		Sleep mode ⁶ , VCC33 = 3.63 V	T _J = 25°C		17	18	μΑ
			T _J = 85°C		18	20	μA
			T _J = 100°C		24	25	μA
ICCI ³	I/O quiescent current	Operational standby ⁶ ,	T _J = 25°C		260	437	μΑ
		VCCIX = 3.63 V	T _J = 85°C		260	437	μΑ
			T _J = 100°C		260	437	μA
IJTAG	JTAG I/O quiescent current	Operational standby ⁴ ,	T _J = 25°C		80	100	μΑ
		VJTAG = 3.63 V	T _J = 85°C		80	100	μA
			T _J = 100°C		80	100	μA
		Standby mode ⁵ or Sleep mode ⁶ , VJTAG = 0 V			0	0	μA
IPP	Programming supply current	Non-programming mode, VPUMP = 3.63 V	T _J = 25°C		37	80	μA
			T _J = 85°C		37	80	μA
			T _J = 100°C		80	100	μA
		Standby mode ⁵ or Sleep mode ⁶ , VPUMP = 0 V			0	0	μA

Notes:

1. ICC is the 1.5 V power supplies, ICC, ICCPLL, ICC15A, ICCNVM.

2. ICC33A includes ICC33A, ICC33PMP, and ICCOSC.

3. ICCI includes all ICCI0, ICCI1, and ICCI2.

4. Operational standby is when the Fusion device is powered up, all blocks are used, no I/O is toggling, Voltage Regulator is loaded with 200 mA, VCC33PMP is ON, XTAL is ON, and ADC is ON.

5. XTAL is configured as high gain, VCC = VJTAG = VPUMP = 0 V.

6. Sleep Mode, VCC = VJTAG = VPUMP = 0 V.

Dynamic Power Consumption of Various Internal Resources

Table 3-14 • Different Components Contributing to the Dynamic Power Consumption in Fusion Devices

		Power	Device-Specific Power Supply Dynamic Contributions					
Parameter	Definition	Name	Setting	AFS1500	AFS600	AFS250	AFS090	Units
PAC1	Clock contribution of a Global Rib	VCC	1.5 V	14.5	12.8	11	11	µW/MHz
PAC2	Clock contribution of a Global Spine	VCC	1.5 V	2.5	1.9	1.6	0.8	µW/MHz
PAC3	Clock contribution of a VersaTile row	VCC	1.5 V		0.8	1		µW/MHz
PAC4	Clock contribution of a VersaTile used as a sequential module	VCC	1.5 V		0.1	1		µW/MHz
PAC5	First contribution of a VersaTile used as a sequential module	VCC	1.5 V		0.0	7		µW/MHz
PAC6	Second contribution of a VersaTile used as a sequential module	VCC	1.5 V		0.2	9		µW/MHz
PAC7	Contribution of a VersaTile used as a combinatorial module	VCC	1.5 V	0.29				µW/MHz
PAC8	Average contribution of a routing net	VCC	1.5 V	0.70				µW/MHz
PAC9	Contribution of an I/O input pin (standard dependent)	VCCI	See Table 3-12 on page 3-18					
PAC10	Contribution of an I/O output pin (standard dependent)	VCCI		See	Table 3-13	on page 3	-20	
PAC11	Average contribution of a RAM block during a read operation	VCC	1.5 V		25	5		µW/MHz
PAC12	Average contribution of a RAM block during a write operation	VCC	1.5 V		30)		µW/MHz
PAC13	Dynamic Contribution for PLL	VCC	1.5 V		2.6	6		µW/MHz
PAC15	Contribution of NVM block during a read operation (F < $33MHz$)	VCC	1.5 V		35	8		µW/MHz
PAC16	1st contribution of NVM block during a read operation (F > 33 MHz)	VCC	1.5 V	12.88			12.88	
PAC17	2nd contribution of NVM block during a read operation (F > 33 MHz)	VCC	1.5 V	V 4.8				µW/MHz
PAC18	Crystal Oscillator contribution	VCC33A	3.3 V	0.63				mW
PAC19	RC Oscillator contribution	VCC33A	3.3 V	3.3 V 3.3		mW		
PAC20	Analog Block dynamic power contribution of ADC	VCC	1.5 V		3			mW

Methodology

Total Power Consumption—PTOTAL

Operating Mode, Standby Mode, and Sleep Mode

 $P_{TOTAL} = P_{STAT} + P_{DYN}$

P_{STAT} is the total static power consumption.

P_{DYN} is the total dynamic power consumption.

Total Static Power Consumption—P_{STAT}

Operating Mode

 $\label{eq:pstat} \begin{array}{l} \mathsf{P}_{\mathsf{STAT}} = \mathsf{PDC1} + (\mathsf{N}_{\mathsf{NVM-BLOCKS}} * \mathsf{PDC4}) + \mathsf{PDC5} + (\mathsf{N}_{\mathsf{QUADS}} * \mathsf{PDC6}) + (\mathsf{N}_{\mathsf{INPUTS}} * \mathsf{PDC7}) + (\mathsf{N}_{\mathsf{OUTPUTS}} * \mathsf{PDC8}) + (\mathsf{N}_{\mathsf{PLLS}} * \mathsf{PDC9}) \end{array}$

 $N_{\ensuremath{\mathsf{NVM}}\xspace-BLOCKS}$ is the number of NVM blocks available in the device.

 N_{QUADS} is the number of Analog Quads used in the design.

N_{INPUTS} is the number of I/O input buffers used in the design.

N_{OUTPUTS} is the number of I/O output buffers used in the design.

N_{PLLS} is the number of PLLs available in the device.

Standby Mode

P_{STAT} = PDC2

Sleep Mode

P_{STAT} = PDC3

Total Dynamic Power Consumption—P_{DYN}

Operating Mode

P_{DYN} = P_{CLOCK} + P_{S-CELL} + P_{C-CELL} + P_{NET} + P_{INPUTS} + P_{OUTPUTS} + P_{MEMORY} + P_{PLL} + P_{NVM}+ P_{XTL-OSC} + P_{RC-OSC} + P_{AB}

Standby Mode

 $P_{DYN} = P_{XTL-OSC}$

Sleep Mode

 $P_{DYN} = 0 W$

Global Clock Dynamic Contribution—P_{CLOCK}

Operating Mode

 $P_{CLOCK} = (PAC1 + N_{SPINE} * PAC2 + N_{ROW} * PAC3 + N_{S-CELL} * PAC4) * F_{CLK}$

N_{SPINE} is the number of global spines used in the user design—guidelines are provided in the "Spine Architecture" section of the Global Resources chapter in the *Fusion and Extended Temperature Fusion FPGA Fabric User's Guide*.

N_{ROW} is the number of VersaTile rows used in the design—guidelines are provided in the "Spine Architecture" section of the Global Resources chapter in the *Fusion and Extended Temperature Fusion FPGA Fabric User's Guide*.

 $\mathsf{F}_{\mathsf{CLK}}$ is the global clock signal frequency.

N_{S-CELL} is the number of VersaTiles used as sequential modules in the design.

Standby Mode and Sleep Mode

 $P_{CLOCK} = 0 W$

Sequential Cells Dynamic Contribution—P_{S-CELL}

Operating Mode

Fusion Family of Mixed Signal FPGAs

	PQ208		PQ208					
Pin Number	AFS250 Function	AFS600 Function	Pin Number	AFS250 Function	AFS600 Function			
74	AV2	AV4	111	VCCNVM	VCCNVM			
75	AC2	AC4	112	VCC	VCC			
76	AG2	AG4	112	VCC	VCC			
77	AT2	AT4	113	VPUMP	VPUMP			
78	ATRTN1	ATRTN2	114	GNDQ	NC			
79	AT3	AT5	115	VCCIB1	ТСК			
80	AG3	AG5	116	ТСК	TDI			
81	AC3	AC5	117	TDI	TMS			
82	AV3	AV5	118	TMS	TDO			
83	AV4	AV6	119	TDO	TRST			
84	AC4	AC6	120	TRST	VJTAG			
85	AG4	AG6	121	VJTAG	IO57NDB2V0			
86	AT4	AT6	122	IO57NDB1V0	GDC2/IO57PDB2V0			
87	ATRTN2	ATRTN3	123	GDC2/IO57PDB1V0	IO56NDB2V0			
88	AT5	AT7	124	IO56NDB1V0	GDB2/IO56PDB2V0			
89	AG5	AG7	125	GDB2/IO56PDB1V0	IO55NDB2V0			
90	AC5	AC7	126	VCCIB1	GDA2/IO55PDB2V0			
91	AV5	AV7	127	GND	GDA0/IO54NDB2V0			
92	NC	AV8	128	IO55NDB1V0	GDA1/IO54PDB2V0			
93	NC	AC8	129	GDA2/IO55PDB1V0	VCCIB2			
94	NC	AG8	130	GDA0/IO54NDB1V0	GND			
95	NC	AT8	131	GDA1/IO54PDB1V0	VCC			
96	NC	ATRTN4	132	GDB0/IO53NDB1V0	GCA0/IO45NDB2V0			
97	NC	AT9	133	GDB1/IO53PDB1V0	GCA1/IO45PDB2V0			
98	NC	AG9	134	GDC0/IO52NDB1V0	GCB0/IO44NDB2V0			
99	NC	AC9	135	GDC1/IO52PDB1V0	GCB1/IO44PDB2V0			
100	NC	AV9	136	IO51NSB1V0	GCC0/IO43NDB2V			
101	GNDAQ	GNDAQ			0			
102	VCC33A	VCC33A	137	VCCIB1	GCC1/IO43PDB2V0			
103	ADCGNDREF	ADCGNDREF	138	GND	IO42NDB2V0			
104	VAREF	VAREF	139	VCC	IO42PDB2V0			
105	PUB	PUB	140	IO50NDB1V0	IO41NDB2V0			
106	VCC33A	VCC33A	141	IO50PDB1V0	GCC2/IO41PDB2V0			
107	GNDA	GNDA	142	GCA0/IO49NDB1V0	VCCIB2			
108	PTEM	PTEM	143	GCA1/IO49PDB1V0	GND			
109	PTBASE	PTBASE	144	GCB0/IO48NDB1V0	VCC			
110	GNDNVM	GNDNVM	145	GCB1/IO48PDB1V0	IO40NDB2V0			
		L]	146	GCC0/IO47NDB1V0	GCB2/IO40PDB2V0			



Package Pin Assignments

PQ208			PQ208		
Pin Number	AFS250 Function	AFS600 Function	Pin Number	AFS250 Function	AFS600 Function
147	GCC1/IO47PDB1V0	IO39NDB2V0	184	IO18RSB0V0	IO10PPB0V1
148	IO42NDB1V0	GCA2/IO39PDB2V0	185	IO17RSB0V0	IO09PPB0V1
149	GBC2/IO42PDB1V0	IO31NDB2V0	186	IO16RSB0V0	IO10NPB0V1
150	VCCIB1	GBB2/IO31PDB2V0	187	IO15RSB0V0	IO09NPB0V1
151	GND	IO30NDB2V0	188	VCCIB0	IO08PPB0V1
152	VCC	GBA2/IO30PDB2V0	189	GND	IO07PPB0V1
153	IO41NDB1V0	VCCIB2	190	VCC	IO08NPB0V1
154	GBB2/IO41PDB1V0	GNDQ	191	IO14RSB0V0	IO07NPB0V1
155	IO40NDB1V0	VCOMPLB	192	IO13RSB0V0	IO06PPB0V0
156	GBA2/IO40PDB1V0	VCCPLB	193	IO12RSB0V0	IO05PPB0V0
157	GBA1/IO39RSB0V0	VCCIB1	194	IO11RSB0V0	IO06NPB0V0
158	GBA0/IO38RSB0V0	GNDQ	195	IO10RSB0V0	IO04PPB0V0
159	GBB1/IO37RSB0V0	GBB1/IO27PPB1V1	196	IO09RSB0V0	IO05NPB0V0
160	GBB0/IO36RSB0V0	GBA1/IO28PPB1V1	197	IO08RSB0V0	IO04NPB0V0
161	GBC1/IO35RSB0V0	GBB0/IO27NPB1V1	198	IO07RSB0V0	GAC1/IO03PDB0V0
162	VCCIB0	GBA0/IO28NPB1V1	199	IO06RSB0V0	GAC0/IO03NDB0V0
163	GND	VCCIB1	200	GAC1/IO05RSB0V0	VCCIB0
164	VCC	GND	201	VCCIB0	GND
165	GBC0/IO34RSB0V0	VCC	202	GND	VCC
166	IO33RSB0V0	GBC1/IO26PDB1V1	203	VCC	GAB1/IO02PDB0V0
167	IO32RSB0V0	GBC0/IO26NDB1V1	204	GAC0/IO04RSB0V0	GAB0/IO02NDB0V0
168	IO31RSB0V0	IO24PPB1V1	205	GAB1/IO03RSB0V0	GAA1/IO01PDB0V0
169	IO30RSB0V0	IO23PPB1V1	206	GAB0/IO02RSB0V0	GAA0/IO01NDB0V0
170	IO29RSB0V0	IO24NPB1V1	207	GAA1/IO01RSB0V0	GNDQ
171	IO28RSB0V0	IO23NPB1V1	208	GAA0/IO00RSB0V0	VCCIB0
172	IO27RSB0V0	IO22PPB1V0			
173	IO26RSB0V0	IO21PPB1V0			
174	IO25RSB0V0	IO22NPB1V0			
175	VCCIB0	IO21NPB1V0			
176	GND	IO20PSB1V0			
177	VCC	IO19PSB1V0			
178	IO24RSB0V0	IO14NSB0V1			
179	IO23RSB0V0	IO12PDB0V1			
180	IO22RSB0V0	IO12NDB0V1			
181	IO21RSB0V0	VCCIB0			
182	IO20RSB0V0	GND			
183	IO19RSB0V0	VCC			

Revision	Changes	Page
Revision 3 (continued)	The "RC Oscillator" section was revised to correct a sentence that did not differentiate accuracy for commercial and industrial temperature ranges, which is given in Table 2-9 • Electrical Characteristics of RC Oscillator (SAR 33722).	2-19
	Figure 2-57 • FIFO Read and Figure 2-58 • FIFO Write are new (SAR 34840).	2-72
	The first paragraph of the "Offset" section was removed; it was intended to be replaced by the paragraph following it (SAR 22647).	2-95
	IOL and IOH values for 3.3 V GTL+ and 2.5 V GTL+ were corrected in Table 2-86 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions (SAR 39813).	2-164
	The drive strength, IOL, and IOH for 3.3 V GTL and 2.5 V GTL were changed from 25 mA to 20 mA in the following tables (SAR 37373):	
	Table 2-86 Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions,	2-164
	Table 2-92 • Summary of I/O Timing Characteristics – Software Default Settings	2-167
	Table 2-96 • I/O Output Buffer Maximum Resistances 1	2-169
	Table 2-138 • Minimum and Maximum DC Input and Output Levels	2-199
	Table 2-141 • Minimum and Maximum DC Input and Output Levels	2-200
	The following sentence was deleted from the "2.5 V LVCMOS" section (SAR 34800): "It uses a 5 V-tolerant input buffer and push-pull output buffer."	2-181
	Corrected the inadvertent error in maximum values for LVPECL VIH and VIL and revised them to "3.6" in Table 2-171 • Minimum and Maximum DC Input and Output Levels, making these consistent with Table 3-1 • Absolute Maximum Ratings, and Table 3-4 • Overshoot and Undershoot Limits 1 (SAR 37687).	2-211
	The maximum frequency for global clock parameter was removed from Table 2-5 • AFS1500 Global Resource Timing through Table 2-8 • AFS090 Global Resource Timing because a frequency on the global is only an indication of what the global network can do. There are other limiters such as the SRAM, I/Os, and PLL. SmartTime software should be used to determine the design frequency (SAR 36955).	2-16 to 2-17
Revision 2 (March 2012)	The phrase "without debug" was removed from the "Soft ARM Cortex-M1 Fusion Devices (M1)" section (SAR 21390).	I
	The "In-System Programming (ISP) and Security" section, "Security" section, "Flash Advantages" section, and "Security" section were revised to clarify that although no existing security measures can give an absolute guarantee, Microsemi FPGAs implement the best security available in the industry (SAR 34679).	l, 1-2, 2-228
	The Y security option and Licensed DPA Logo was added to the "Product Ordering Codes" section. The trademarked Licensed DPA Logo identifies that a product is covered by a DPA counter-measures license from Cryptography Research (SAR 34721).	III
	The "Specifying I/O States During Programming" section is new (SAR 34693).	1-9
	The following information was added before Figure 2-17 • XTLOSC Macro:	2-20
	In the case where the Crystal Oscillator block is not used, the XTAL1 pin should be connected to GND and the XTAL2 pin should be left floating (SAR 24119).	
	Table 2-12 • Fusion CCC/PLL Specification was updated. A note was added indicating that when the CCC/PLL core is generated by Microsemi core generator software, not all delay values of the specified delay increments are available (SAR 34814).	2-28



Datasheet Information

Revision	Changes	Page
Advance v1.0 (continued)	This change table states that in the "208-Pin PQFP" table listed under the Advance v0.8 changes, the AFS090 device had a pin change. That is incorrect. Pin 102 was updated for AFS250 and AFS600. The function name changed from $V_{CC33ACAP}$ to V_{CC33A} .	3-8
Advance v0.9 (October 2007)	In the "Package I/Os: Single-/Double-Ended (Analog)" table, the AFS1500/M7AFS1500 I/O counts were updated for the following devices: FG484: 223/109 FG676: 252/126	II
	In the "108-Pin QFN" table, the function changed from $V_{CC33ACAP}$ to V_{CC33A} for the following pin: B25	3-2
	In the "180-Pin QFN" table, the function changed from V _{CC33ACAP} to V _{CC33A} for the following pins: AFS090: B29 AFS250: B29	3-4
	In the "208-Pin PQFP" table, the function changed from V _{CC33ACAP} to V _{CC33A} for the following pins: AFS090: 102 AFS250: 102	3-8
	In the "256-Pin FBGA" table, the function changed from $V_{CC33ACAP}$ to V_{CC33A} for the following pins: AFS090: T14 AFS250: T14 AFS600: T14 AFS1500: T14	3-12
Advance v0.9 (continued)	In the "484-Pin FBGA" table, the function changed from V _{CC33ACAP} to V _{CC33A} for the following pins: AFS600: AB18 AFS1500: AB18	3-20
	In the "676-Pin FBGA" table, the function changed from V _{CC33ACAP} to V _{CC33A} for the following pins: AFS1500: AD20	3-28
Advance v0.8 (June 2007)	Figure 2-16 • Fusion Clocking Options and the "RC Oscillator" section were updated to change GND_OSC and VCC_OSC to GNDOSC and VCCOSC.	2-20, 2-21
	Figure 2-19 • Fusion CCC Options: Global Buffers with the PLL Macro was updated to change the positions of OADIVRST and OADIVHALF, and a note was added.	2-25
	The "Crystal Oscillator" section was updated to include information about controlling and enabling/disabling the crystal oscillator.	2-22
	Table 2-11 \cdot Electrical Characteristics of the Crystal Oscillator was updated to change the typical value of I _{DYNXTAL} for 0.032–0.2 MHz to 0.19.	2-24
	The "1.5 V Voltage Regulator" section was updated to add "or floating" in the paragraph stating that an external pull-down is required on TRST to power down the VR.	2-41
	The "1.5 V Voltage Regulator" section was updated to include information on powering down with the VR.	2-41